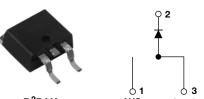
HALOGEN

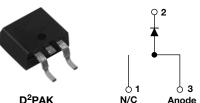
FREE



Vishay High Power Products

HEXFRED® Ultrafast Soft Recovery Diode, 16 A





PRODUCT SUMMARY V_R 1200 V V_F at 16 A at 25 °C 3 V 16 A I_{F(AV)} t_{rr} (typical) 30 ns T_J (maximum) 150 °C Q_{rr} (typical) 260 nC

76 A/µs

5.8 A

dI_{(rec)M}/dt (typical) at 125 °C

I_{RRM} (typical)

FEATURES

- Ultrafast recovery
- Ultrasoft recovery
- Very low I_{RRM}
- Very low Q_{rr}
- Specified at operating conditions
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Halogen-free according to IEC 61249-2-21 definition
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level

BENEFITS

- · Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION

VS-HFA16TB120SPbF is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 V and 16 A continuous current, the VS-HFA16TB120SPbF is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA16TB120SPbF is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL TEST CONDITIONS		MAX.	UNITS		
Cathode to anode voltage	V_R		1200	V		
Maximum continuous forward current	I _F	T _C = 100 °C	16			
Single pulse forward current	I _{FSM}		190	Α		
Maximum repetitive forward current	I _{FRM}		64]		
Maximum power dissipation	P _D	T _C = 25 °C	151	W		
Maximum power dissipation		T _C = 100 °C	60	VV		
Operating junction and storage temperature range	T_J , T_{Stg}		- 55 to + 150	°C		

VS-HFA16TB120SPbF

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ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	Ι _R = 100 μΑ		1200	-	-	
	V _{FM}	I _F = 16 A		-	2.5	3.0	V
Maximum forward voltage		I _F = 32 A	See fig. 1	-	3.2	3.93	
		I _F = 16 A, T _J = 125 °C		-	2.3	2.7	
Maximum reverse		V _R = V _R rated	See fig. 2	-	0.75	20	μA
leakage current	I _{RM}	$T_J = 125$ °C, $V_R = 0.8 \times V_R$ rated	See fig. 2	-	375	2000	μΑ
Junction capacitance	C _T	V _R = 200 V See fig. 3		-	27	40	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body - 8.0 -			nΗ		

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
	t _{rr}	$I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	30	-	
Reverse recovery time See fig. 5 and 10	t _{rr1}	T _J = 25 °C	$I_F = 16 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 200 \text{ V}$	-	90	135	ns
See lig. 5 and 10	t _{rr2}	T _J = 125 °C		-	164	245	
Peak recovery current See fig. 6	I _{RRM1}	T _J = 25 °C		-	5.8	10	A nC
	I _{RRM2}	T _J = 125 °C		-	8.3	15	
Reverse recovery charge See fig. 7	Q _{rr1}	T _J = 25 °C		-	260	675	
	Q _{rr2}	T _J = 125 °C		-	680	1838	IIC
Peak rate of fall of recovery current during t _b See fig. 8	dI _{(rec)M} /dt1	T _J = 25 °C		-	120	-	- A/μs
	dI _{(rec)M} /dt2	T _J = 125 °C		-	76	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		TYP.	MAX.	UNITS
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s		-	300	°C
Thermal resistance, junction to case	R _{thJC}		-	-	0.83	K/W
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	80	7 7/1/1
Weight			-	2.0	-	g
Weight			-	0.07	-	oz.
Marking device		Case style D ² PAK		HFA16	TB120S	





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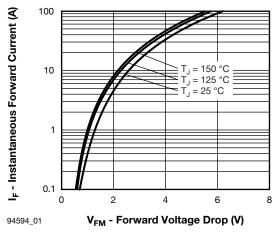


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current (Per Leg)

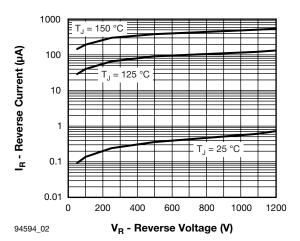


Fig. 2 - Typical Reverse Current vs. Reverse Voltage (Per Leg)

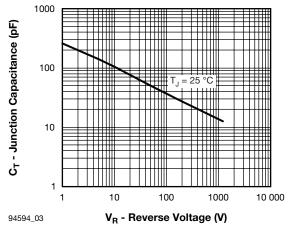


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

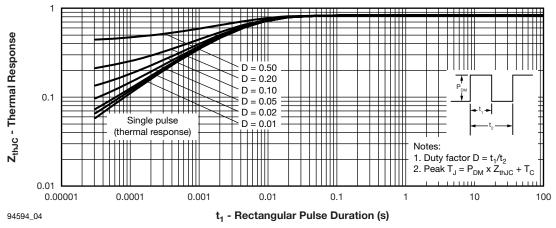


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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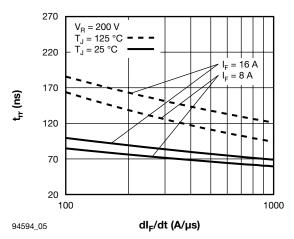


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt (Per Leg)

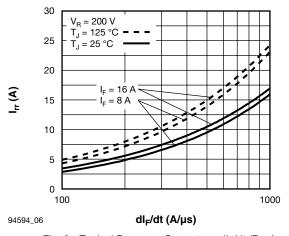


Fig. 6 - Typical Recovery Current vs. dI_F/dt (Per Leg)

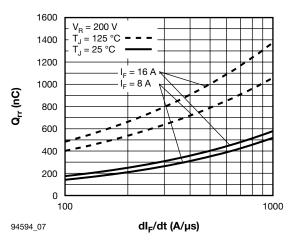


Fig. 7 - Typical Stored Charge vs. dI_F/dt (Per Leg)

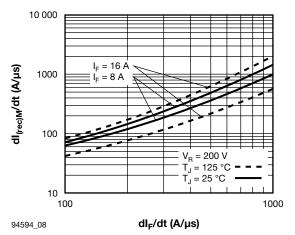


Fig. 8 - Typical $dI_{(rec)M}/dt$ vs. dI_F/dt (Per Leg)



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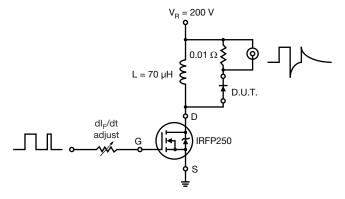
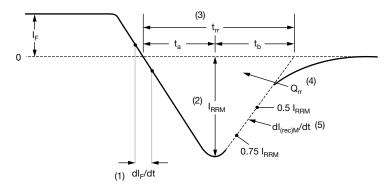


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) $\rm Q_{rr}$ area under curve defined by $\rm t_{rr}$ and $\rm I_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions

VS-HFA16TB120SPbF

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HEXFRED® Ultrafast Soft Recovery Diode, 16 A



ORDERING INFORMATION TABLE

Device code

VS-	HF	A	16	ТВ	120	s	TRL	PbF
1	2	3	4	5	6	7	8	9

- 1 HPP product suffix
- 2 HEXFRED® family
- Process designator: A = Electron irradiated
- 4 Current rating (16 = 16 A)
- 5 Package outline (TB = TO-220, 2 leads)
- 6 Voltage rating (120 = 1200 V)
- $7 S = D^2PAK$
- None = Tube (50 pieces)
 - TRL = Tape and reel (left oriented)
 - TRR = Tape and reel (right oriented)
- 9 PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95046				
Part marking information	www.vishay.com/doc?95054				
Packaging information	www.vishay.com/doc?95032				



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